

N- and P-Channel 30 V (D-S) MOSFET

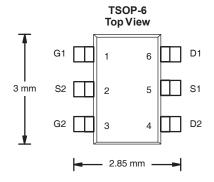
PRODUCT SUMMARY						
	V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)			
N-Channel	30	$0.028 \text{ at V}_{GS} = 10 \text{ V}$	4.2			
N-Channel		0.043 at $V_{GS} = 4.5 \text{ V}$	3.0			
P-Channel	- 30	0.042 at V _{GS} = - 10 V	- 3.1			
P-Channel		0.053 at V _{GS} = - 4.5 V	- 2.3			

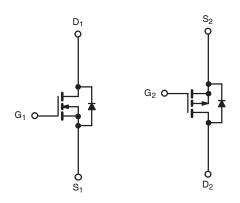
FEATURES

- DT-Trench Power MOSFET
- 100 % R_g Tested
- Compliant to RoHS Directive 2002/95/EC



RoHS





N-Channel MOSFET

P-Channel MOSFET

ABSOLUTE MAXIMUM RATING	GS T _A = 25 °	°C, unless other	wise noted		
Parameter	Symbol	N-Channel	P-Channel	Unit	
Drain-Source Voltage		V _{DS}	30	- 30	٧
Gate-Source Voltage		V _{GS}	± 20	± 20	
Ocation and Ducin Comment /T 150 20\alpha.b	T _A = 25 °C	- I _D	4.2	- 3.0	
Continuous Drain Current (T _J = 150 °C) ^{a, b}	T _A = 70 °C		3.1	- 2.3	
Pulsed Drain Current		I _{DM}	10	- 7	А
Continuous Source Current (Diode Conduction) ^{a, b}		I _S	4.2	- 3.0	
a h	T _A = 25 °C	D	1.15		W
Maximum Power Dissipation ^{a, b}	T _A = 70 °C	P_{D}	0.73		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Manianum lumation to Ambient	t ≤ 5 s	R_{thJA}	93	110	°C/W	
Maximum Junction-to-Ambient ^a	Steady State		130	150		
Maximum Junction-to-Lead	Steady State	R_{thJL}	75	90		

Notes:

a. Surface Mounted on FR4 board.

 $b.\ t \leq 5\ s.$



Parameter	Symbol	ol Test Conditions		Min.	Тур.	Max.	Unit	
Static								
Cata Threehold Voltage	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	N-Ch	0.6		2.0	.,	
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = - 250 μA	P-Ch	Ch - 0.6		-1.5	V	
Gate-Body Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 20 V	N-Ch P-Ch			± 100 ± 100	nA	
		V _{DS} = 24 V, V _{GS} = 0 V				1	1	
7 0		V _{DS} = - 24 V, V _{GS} = 0 V	P-Ch			- 1	- μΑ	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 24 V, V _{GS} = 0 V, T _J = 55 °C	N-Ch			5		
		V _{DS} = - 24 V, V _{GS} = 0 V, T _J = 55 °C	P-Ch			- 5		
		V _{DS} = 5 V, V _{GS} = 10 V	N-Ch	4.2				
On-State Drain Current ^a	I _{D(on)}	V _{DS} = - 5 V, V _{GS} = - 10 V	P-Ch	- 3.1			Α	
		V _{GS} = 10 V, I _D = 2.5 A	N-Ch		0.028	0.035	Ω	
Dunin Course On Otata Desistance	B	V _{GS} = - 10 V, I _D = - 1.8 A	P-Ch		0.043	0.056		
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 2.0 \text{ A}$	N-Ch		0.042	0.050	. (2	
		$V_{GS} = -4.5 \text{ V}, I_D = -1.2 \text{ A}$	P-Ch		0.053	0.065		
	9 _{fs}	V _{DS} = 10 V, I _D = 2.5 A N-Ch			4.3		S	
Forward Transconductance ^a		V _{DS} = - 15 V, I _D = - 1.8 A	P-Ch		2.4			
Diode Forward Voltage ^a	V _{SD}	I _S = 1.05 A, V _{GS} = 0 V	N-Ch		0.81	1.10	V	
		I _S = - 1.05 A, V _{GS} = 0 V	P-Ch		- 0.83	- 1.10		
Dynamic ^b								
Total Gate Charge	Q_g	N-Channel	N-Ch		2.1	3.2		
	g	$V_{DS} = 15 \text{ V}, V_{GS} = 5 \text{ V}, I_{D} = 1.8 \text{ A}$	P-Ch		2.4	3.6	nC	
Gate-Source Charge	Q_{gs}		N-Ch P-Ch		0.7 0.9			
		P-Channel V _{DS} = - 15 V, V _{GS} = - 5 V, I _D = - 1.8 A	N-Ch		0.9			
Gate-Drain Charge	Q_{gd}	V _{DS} = - 15 V, V _{GS} = - 5 V, I _D = - 1.6 A	P-Ch		0.8			
Cata Pagistanas	P		N-Ch	0.5		2.4		
Gate Resistance	R _g		P-Ch	3		11	Ω	
Turn-On Delay Time	t _{d(on)}	N-Channel	N-Ch		7	11		
		$V_{DD} = 15 \text{ V}, R_L = 15 \Omega$	P-Ch		8	12	-	
Rise Time		$I_D \cong 1 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 6 \Omega$	N-Ch P-Ch		9 12	14 18		
Turn-Off Delay Time	t _{d(off)}	-	N-Ch		13	20		
		P-Channel V_{DD} = - 15 V, R_L = 15 Ω	P-Ch		12	18	ns	
E-II The	t _f	$I_D \cong -1 \text{ A}, V_{GEN} = -10 \text{ V}, R_q = 6 \Omega$	N-Ch		5	8		
Fall Time		S ALIV , g	P-Ch		7	11		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 1.05 A, dI/dt = 100 A/μs	N-Ch		35	60		
Source-Dialit neverse necovery Time		I _F = - 1.05 A, dl/dt = 100 A/μs	P-Ch		30	60		

Notes:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

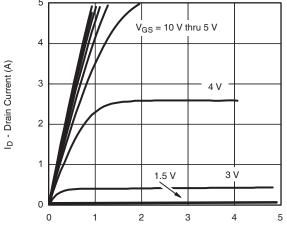
a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$

b. Guaranteed by design, not subject to production testing.

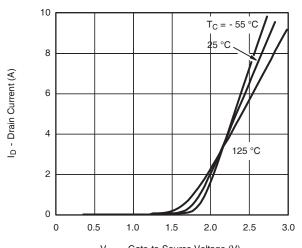


N-CHANNEL TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

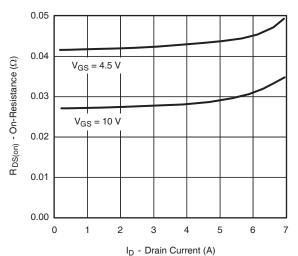
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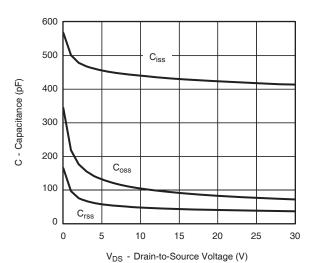
V_{DS} - Drain-to-Source Voltage (V) **Output Characteristics**



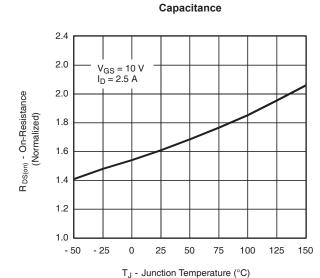
V_{GS} - Gate-to-Source Voltage (V) **Transfer Characteristics**



On-Resistance vs. Drain Current







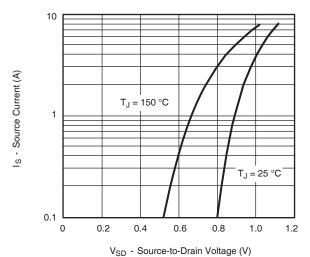
On-Resistance vs. Junction Temperature

Gate Charge

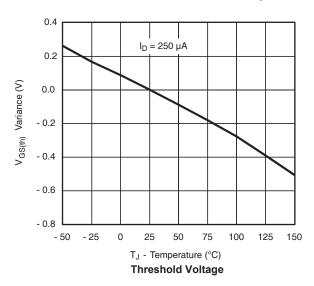


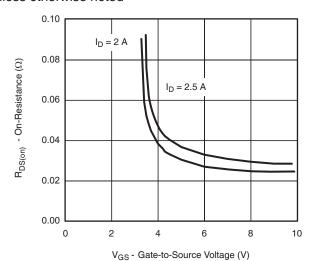
N-CHANNEL TYPICAL CHARACTERISTICS $25\ ^{\circ}\text{C}$, unless otherwise noted

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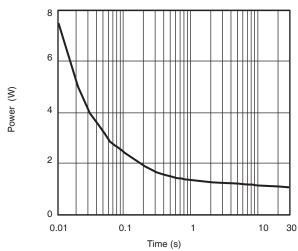


Source-Drain Diode Forward Voltage

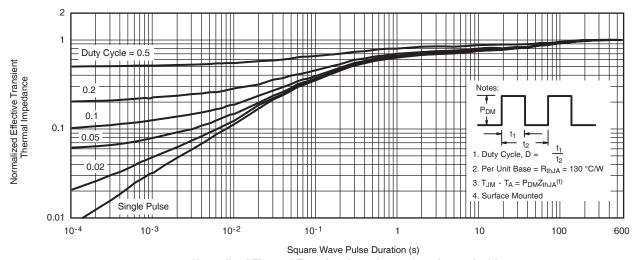




On-Resistance vs. Gate-to-Source Voltage

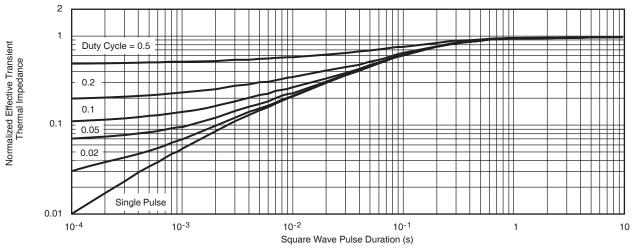


Single Pulse Power (Junction-to-Ambient)



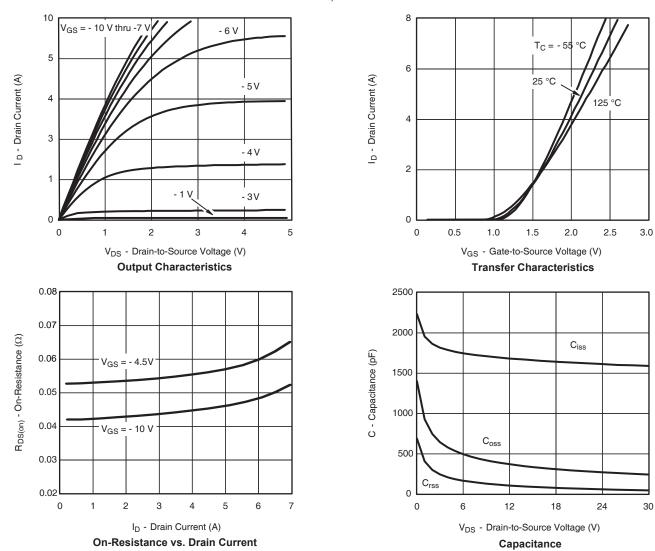
Normalized Thermal Transient Impedance, Junction-to-Ambient

N-CHANNEL TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot

P-CHANNEL TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

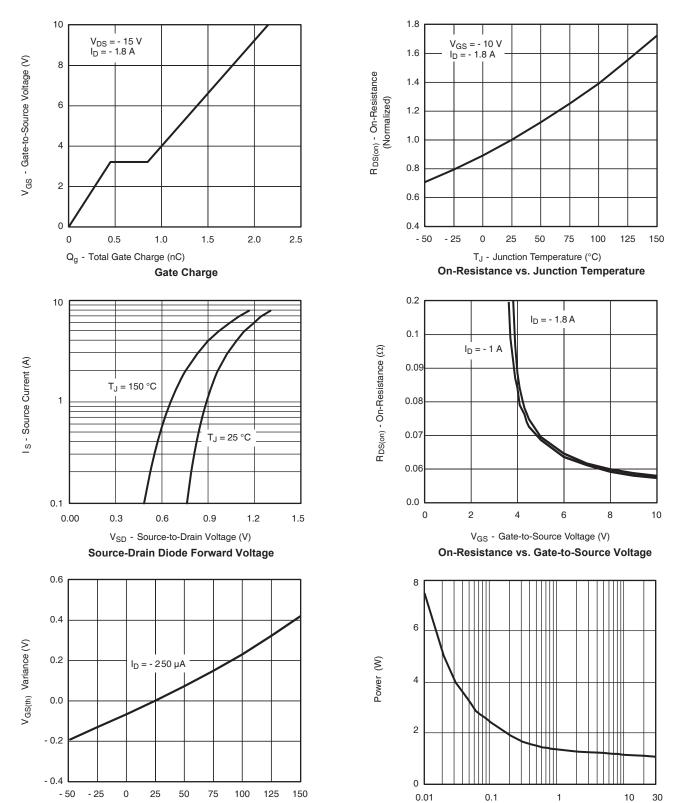


P-CHANNEL TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

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Time (s)

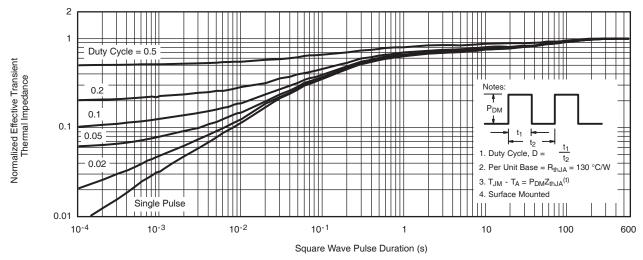
Single Pulse Power (Junction-to-Ambient)



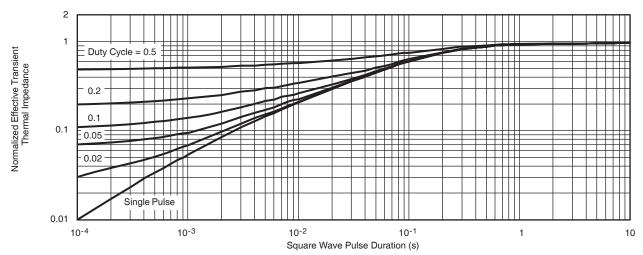
T_J - Temperature (°C)

Threshold Voltage

P-CHANNEL TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Ambient



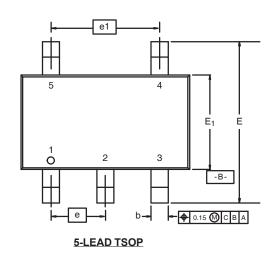
Normalized Thermal Transient Impedance, Junction-to-Foot

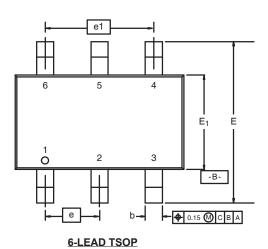


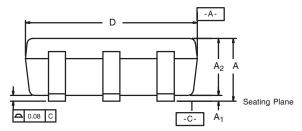


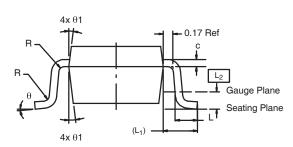
TSOP: 5/6-LEAD

JEDEC Part Number: MO-193C





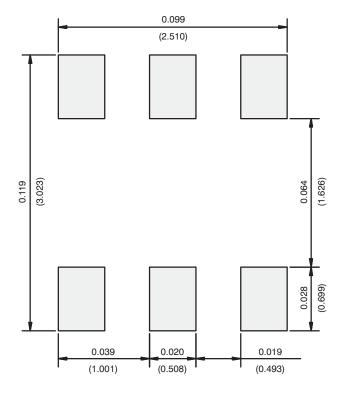




	MILLIMETERS			INCHES			
Dim	Min	Nom	Max	Min	Nom	Max	
Α	0.91	-	1.10	0.036	-	0.043	
A ₁	0.01	-	0.10	0.0004	-	0.004	
A ₂	0.90	-	1.00	0.035	0.038	0.039	
b	0.30	0.32	0.45	0.012	0.013	0.018	
С	0.10	0.15	0.20	0.004	0.006	0.008	
D	2.95	3.05	3.10	0.116	0.120	0.122	
Е	2.70	2.85	2.98	0.106	0.112	0.117	
E ₁	1.55	1.65	1.70	0.061	0.065	0.067	
е		0.95 BSC		0.0374 BSC			
e ₁	1.80	1.90	2.00	0.071	0.075	0.079	
L	0.32	-	0.50	0.012	-	0.020	
L ₁	0.60 Ref			0.024 Ref			
L ₂	0.25 BSC			0.010 BSC			
R	0.10	-	-	0.004	-	-	
θ	0°	4°	8°	0°	4°	8°	
θ_1	7° Nom			7° Nom			
ECN: C-06593-Rev. I, 18-Dec-06 DWG: 5540							

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RECOMMENDED MINIMUM PADS FOR TSOP-6



Recommended Minimum Pads Dimensions in Inches/(mm)





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